SN74AVC2T244 2-Bit Unidirectional Voltage-level Translator

1 Features

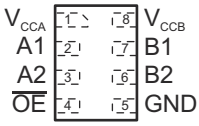
- Wide Operating V_{CC} Range of 0.9 V to 3.6 V
- Low Static-Power Consumption, 6-µA Max I_{CC}
- Output Enable Feature Allows User to Disable Outputs to Reduce Power Consumption
- ±24-mA Output Drive at 3.0 V
- I_{off} Supports Partial Power-Down-Mode Operation
- Input Hysteresis Allows Slow Input Transition and Better Switching Noise Immunity at Input
- Maximum Data Rates
  - 380 Mbps (1.8-V to 3.3-V Translation)
  - 200 Mbps (<1.8-V to 3.3-V Translation)
  - 200 Mbps (Translate to 2.5 V or 1.8 V)
  - 150 Mbps (Translate to 1.5 V)
  - 100 Mbps (Translate to 1.2 V)
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22
  - 5000-V Human-Body Model (A114-A)

2 Applications

- Handset, Smartphone, Tablet, Server

3 Description

This 2-bit unidirectional translator uses two separate configurable power-supply rails. The A port is designed to track V_{CCA}. V_{CCA} accepts any supply voltage from 0.9 V to 3.6 V. The B port is designed to track V_{CCB}. V_{CCB} accepts any supply voltage from 0.9 V to 3.6 V. This allows for low-voltage translation between 0.9-V, 1.2-V, 1.5-V, 1.8-V, 2.5-V and 3.6-V voltage nodes. For the SN74AVC2T244, when the output-enable ($\overline{OE}$) input is high, all outputs are placed in the high-impedance state. The SN74AVC2T244 is designed so that the $\overline{OE}$ input circuit is referenced to V_{CCA}. This device is fully specified for partial-power-down applications using Ioff. The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.



DQE and DQM Packages 8 Pin X2SON (Top View)

Table of Contents

4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision B (September 2011) to Revision C (March 2021)	Page
• Updated the numbering format for tables, figures, and cross-references throughout the document	1
• Updated the title of the data sheet	1
• Deleted *Ordering Information* table, see POA at the end of the datasheet.	1

5 Pin Configuration and Functions

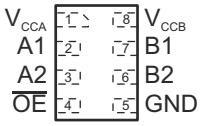


Figure 5-1. DQE and DQM Packages 8 Pin X2SON (Top View)

Table 5-1. Pin Functions

PIN	FUNCTION
VCCA	Input Port DC Power Supply
VCCB	Output Port DC Power Supply
GND	Ground
An	Input Port
Bn	Output Port
OE	Output Enable

6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) (1)

				MIN	MAX	UNIT
Voltage	DC Supply voltage, V_{CCA} V_{CCB}			–0.5	4.6	V
	DC Input voltage, V_I		A_n	–0.5	4.6	V
	Control Input, V_C		$\overline{OE}$	–0.5	4.6	V
	DC Output voltage, V_O, V_{CCA} = V_{CCB} = 0	(Power Down)	B_n	–0.5	4.6	V
		(Active Mode)	B_n	–0.5	4.6	
		3-State Mode	B_n	–0.5	4.6	
	DC Input Diode current, I_{IK}	V_I < GND			–20	mA
	DC Output Diode current, I_{OK}	V_O < GND			–50	mA
	DC Output Source/Sink current, I_O				±50	mA
	DC Supply current per supply pin, I_{CCA}, I_{CCB}				±100	mA
I_{GND}	DC Ground current per ground pin				±100	mA
T_{stg}	Storage temperature range			–65	150	°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

6.2 Recommended Operating Conditions

				MIN	MAX	UNIT
V_{CCA}, V_{CCB}	Positive DC Supply voltage			0.9	3.6	V
V_I	Bus input voltage			GND	3.6	V
V_I	Input voltage			GND	3.6	V
V_C	Control input		$\overline{OE}$	GND	3.6	V
V_O	Bus output voltage	(Power Down Mode)	B_n	GND	3.6	V
		(Active Mode)	B_n	GND	V_{CCB}	V
		3-State Mode	B_n	GND	3.6	V
T_A	Operating free-air temperature			–40	85	°C
Δt/Δv	Input transition rise or fall rate V_I from 30% to 70% of V_{CC}; V_{CC} = 3.3 V ±0.3 V			0	10	nS

6.3 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER[1] [2]		TEST CONDITIONS	V_{CCA} (V)	V_{CCB} (V)	–40°C to 85°C		UNIT
					MIN	MAX	
V_{IH}	Input HIGH Voltage (An, $\overline{OE}$)		2.7 – 3.6	0.9 – 3.6	2.0	–	V
			2.3 – 2.7		1.6	–	
			1.4 – 2.3		0.65 × V_{CCA}	–	
			0.9 – 1.4		0.9 × V_{CCA}	–	
V_{IL}	Input LOW voltage (An, $\overline{OE}$)		2.7 – 3.6	0.9 – 3.6	–	0.8	V
			2.3 – 2.7		–	0.7	
			1.4 – 2.3		–	0.35 × V_{CCA}	
			0.9 – 1.5		–	0.1 × V_{CCA}	
V_{OH}	Output HIGH voltage	I_{OH} = –100 µA; V_I = V_H	0.9 – 3.6	0.9 – 3.6	V_{CCB} – 0.2	–	V
		I_{OH} = –0.5 mA; V_I = V_H	0.9	0.9	0.75 × V_{CCB}	–	
		I_{OH} = –2 mA; V_I = V_H	1.4	1.4	1.05	–	
		I_{OH} = –6 mA; V_I = V_H	1.65	1.65	1.25	–	
			2.3	2.3	2.0	–	
		I_{OH} = –12 mA; V_I = V_H	2.3	2.3	1.8	–	
			2.7	2.7	2.2	–	
		I_{OH} = –18 mA; V_I = V_H	2.3	2.3	1.7	–	
			3.0	3.0	2.4	–	
		I_{OH} = –24 mA; V_I = V_H	3.0	3.0	2.2	–	
V_{OL}	Output LOW voltage	I_{OH} = 100 µA; V_I = V_H	0.9 – 3.6	0.9 – 3.6	–	0.2	V
		I_{OH} = 0.5 mA; V_I = V_H	1.1	1.1	–	0.3	
		I_{OH} = 2 mA; V_I = V_H	1.4	1.4	–	0.35	
		I_{OH} = 6 mA; V_I = V_H	1.65	1.65	–	0.3	
		I_{OH} = 12 mA; V_I = V_H	2.3	2.3	–	0.4	
			2.7	2.7	–	0.4	
		I_{OH} = 18 mA; V_I = V_H	2.3	2.3	–	0.6	
			3.0	3.0	–	0.4	
		I_{OH} = 24 mA; V_I = V_H	3.0	3.0	–	0.55	
I_I	Input Leakage Current	V_I = V_{CCA} or GND	0.9 – 3.6	0.9 – 3.6	–1.0	1.5	µA
I_{OFF}	Power-Off Leakage Current	$\overline{OE}$ = 0V	0	0.9 – 3.6	–1.0	1.3	µA
			0.9 – 3.6	0	–1.0	1.5	
I_{CCA}	Quiescent Supply Current	V_I = V_{CCA} or GND; I_O = 0	0.9 – 3.6	0.9 – 3.6	–	3.0	µA
I_{CCB}	Quiescent Supply Current	V_I = V_{CCA} or GND; I_O = 0	0.9 – 3.6	0.9 – 3.6	–	3.0	µA
I_{CCA} + I_{CCB}	Quiescent Supply Current	V_I = V_{CCA} or GND; I_O = 0	0.9 – 3.6	0.9 – 3.6	–	6.0	µA
ΔI_{CCA}	Increase in I_{CC} per Input Voltage, Other inputs at V_{CCA} or GND	V_I = V_{CCA} – 0.3 V; V_I = V_{CCA} or GND	3.6	3.6	–	5.0	µA

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER[1] [2]		TEST CONDITIONS	V_{CCA} (V)	V_{CCB} (V)	–40°C to 85°C		UNIT
					MIN	MAX	
ΔI_{CCB}	Increase in I_{CC} per Input Voltage, Other inputs at V_{CCA} or GND	$V_I = V_{CCA} – 0.3$ V; $V_I = V_{CCA}$ or GND	3.6	3.6	–	5.0	µA
I_{OZ}	I/O Tri-State Output Leakage Current	TA = 25°C, $\overline{OE}$ = 0 V	0.9 – 3.6	0.9 – 3.6	–1.0	1.0	µA

(1) V_{CCO} is the V_{CC} associated with the output port.
(2) V_{CCI} is the V_{CC} associated with the input port.

6.4 AC Electrical Characteristics

over operating free-air temperature range (unless otherwise noted)

	PARAMETER	V_{CCA} (V)	VCCB (V)	MIN	MAX	UNIT
t_{PLH}, t_{PHL}	Propagation Delay, A_n to B_n	0.9 – 3.6	0.9 – 3.6		20	nS
		1.2 – 3.6	1.2 – 3.6		7	
		1.8 – 3.6	1.8 – 3.6		3.5	
t_{PZH}, t_{PZL}	Output Enable, $\overline{OE}$ to B_n	0.9 – 3.6	0.9 – 3.6		23	nS
		1.2 – 3.6	1.2 – 3.6		6.5	
		1.8 – 3.6	1.8 – 3.6		4.1	
t_{PHZ}, t_{PLZ}	Output Disable, $\overline{OE}$ to B_n	0.9 – 3.6	0.9 – 3.6		17	nS
		1.2 – 3.6	1.2 – 3.6		7	
		1.8 – 3.6	1.8 – 3.6		4.3	
t_{OSHL}, t_{OSLH}	Output to Output Skew, Time	0.9 – 3.6	0.9 – 3.6		0.15	nS
		1.2 – 3.6	1.2 – 3.6		0.15	
		1.8 – 3.6	1.8 – 3.6		0.15	

Table 6-1. Capacitance

[2]	PARAMETER	TEST CONDITIONS	TYP[1]	UNIT
C_{IN}	Control Pin Input Capacitance	$V_{CCA} = V_{CCB} = 3.3$ V, $V_I = 0$ V or $V_{CCA/B}$	3.5	pF
$C_{I/O}$	I/O Pin Input capacitance	$V_{CCA} = V_{CCB} = 3.3$ V, $V_I = 0$ V or $V_{CCA/B}$	5.0	pF
C_{PD}	Power Dissipation Capacitance	$V_{CCA} = V_{CCB} = 3.3$ V, $V_I = 0$ V or $V_{CCA/B}$, f = 10 MHz	33	pF

(1) Typical values are at TA = +25°C.
(2) C_{PD} is defined as the value of the IC's equivalent capacitance from which the operating current can be calculated from: $I_{CC(operating)} \approx C_{PD} \times V_{CC} \times f_{IN} \times N_{SW}$ where $I_{CC} = I_{CCA} + I_{CCB}$ and N_{SW} = total number of outputs switching.

7 Device and Documentation Support

7.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

7.2 Support Resources

TI E2E™ support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

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7.3 Trademarks

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7.4 Electrostatic Discharge Caution

This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

7.5 Glossary

TI Glossary This glossary lists and explains terms, acronyms, and definitions.

8 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
SN74AVC2T244DQER	Active	Production	X2SON (DQE) | 8	5000 | LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	VA
SN74AVC2T244DQER.B	Active	Production	X2SON (DQE) | 8	5000 | LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	VA
SN74AVC2T244DQMR	Active	Production	X2SON (DQM) | 8	3000 | LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	VA
SN74AVC2T244DQMR.B	Active	Production	X2SON (DQM) | 8	3000 | LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	VA

(1) **Status:** For more details on status, see our product life cycle.

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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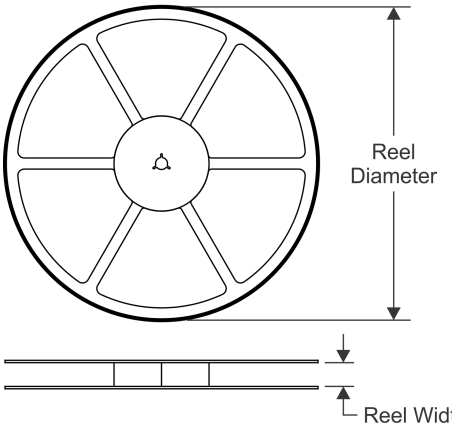
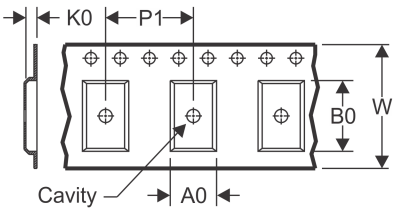
TAPE AND REEL INFORMATION

REEL DIMENSIONS

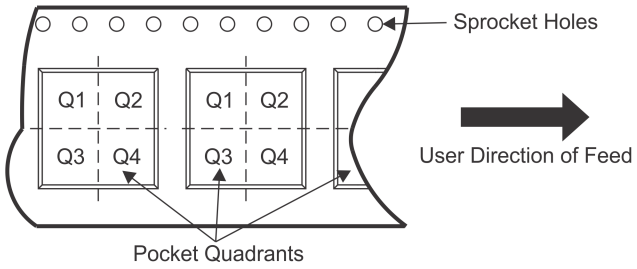


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

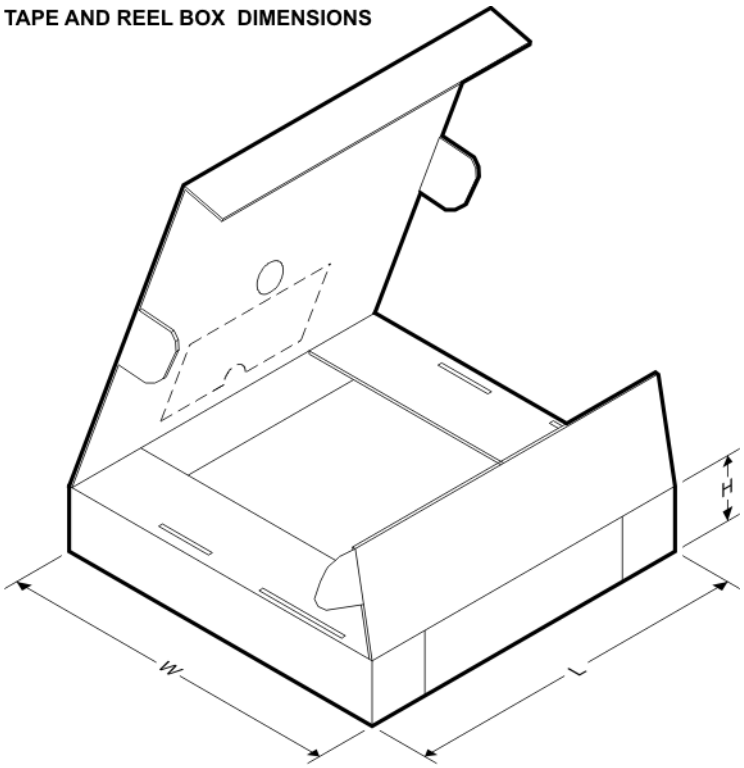
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AVC2T244DQER	X2SON	DQE	8	5000	180.0	8.4	1.2	1.6	0.55	4.0	8.0	Q1
SN74AVC2T244DQMR	X2SON	DQM	8	3000	180.0	8.4	1.57	2.21	0.59	4.0	8.0	Q1

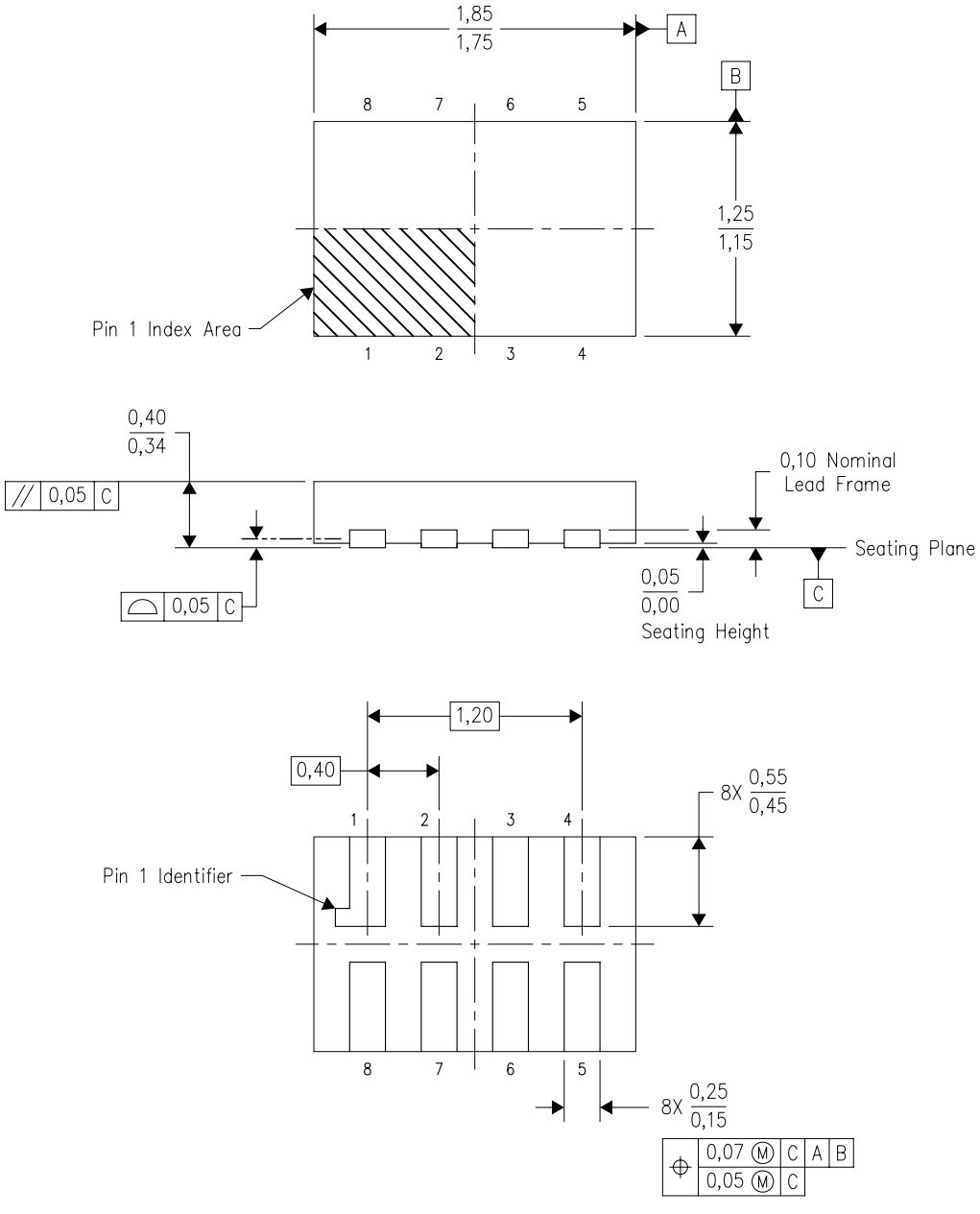
TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74AVC2T244DQER	X2SON	DQE	8	5000	202.0	201.0	28.0
SN74AVC2T244DQMR	X2SON	DQM	8	3000	202.0	201.0	28.0

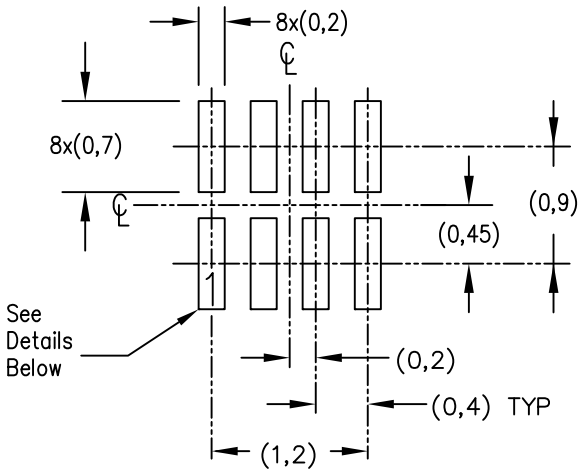
DQM (R–PX2SON–N8) PLASTIC SMALL OUTLINE NO–LEAD



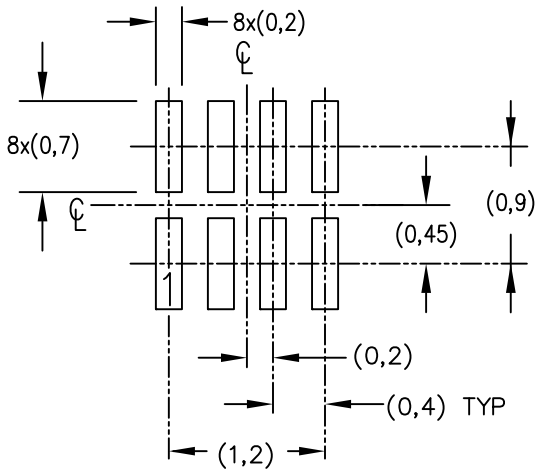
NOTES:
A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M–1994.
B. This drawing is subject to change without notice.
C. SON (Small Outline No–Lead) package configuration.

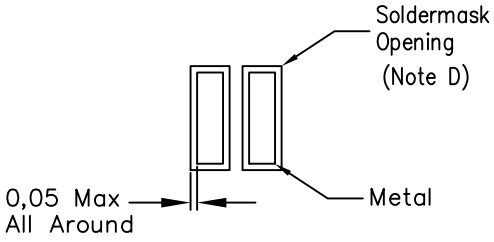
DQM (R–PX2SON–N8) PLASTIC SMALL OUTLINE NO–LEAD

Example Board Layout

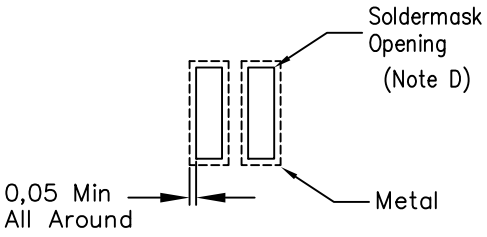


Example Stencil Design
0.1mm Thick Stencil
(Note C)





Non Solder Mask Defined Pad



Solder Mask Defined Pad

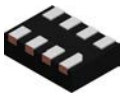
Solder Mask Details

4218746/A 07/13

NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
D. Customers should contact their board fabrication site for recommended solder mask tolerances.

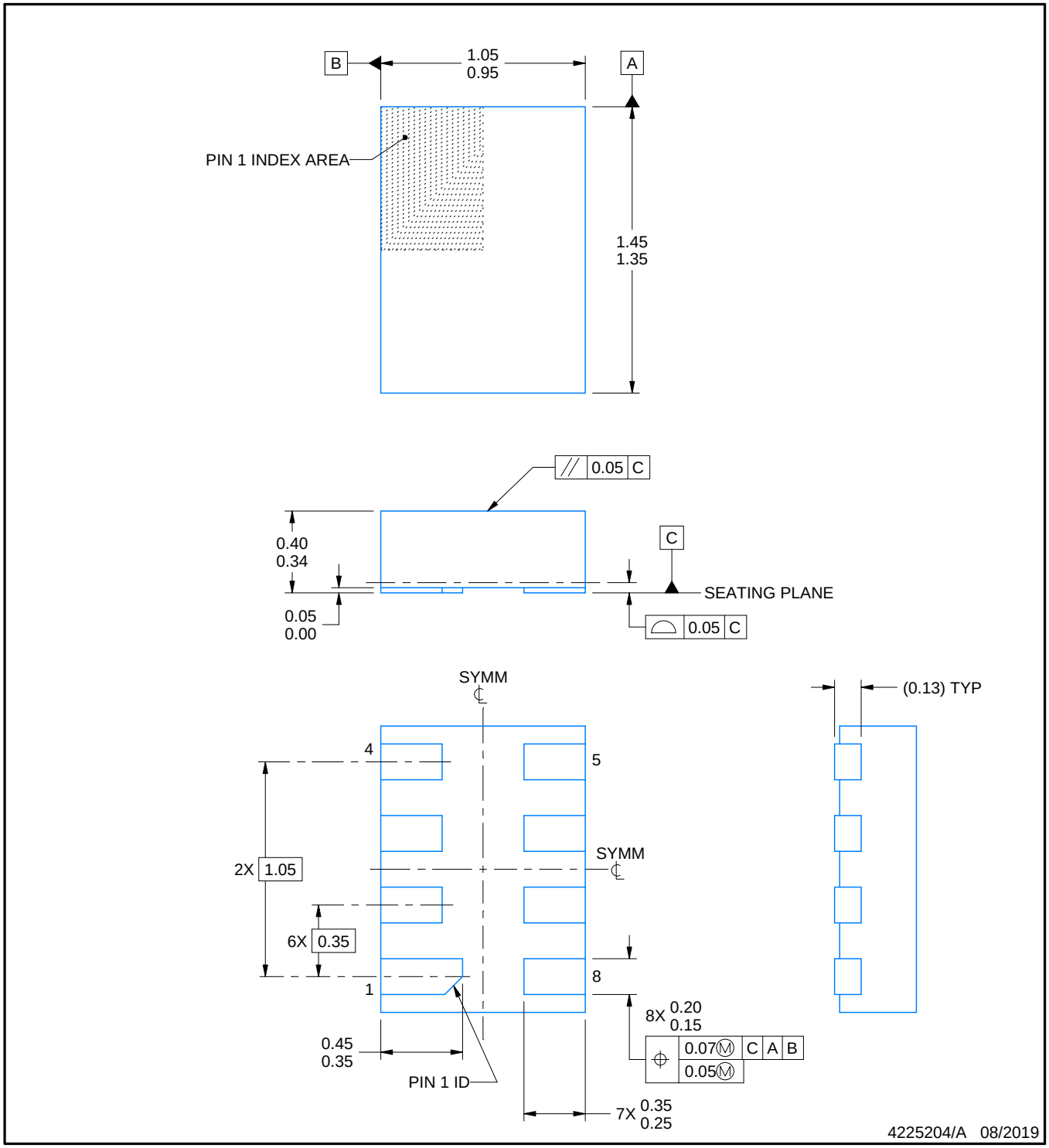
PACKAGE OUTLINE

DQE0008A



X2SON - 0.4 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



NOTES:

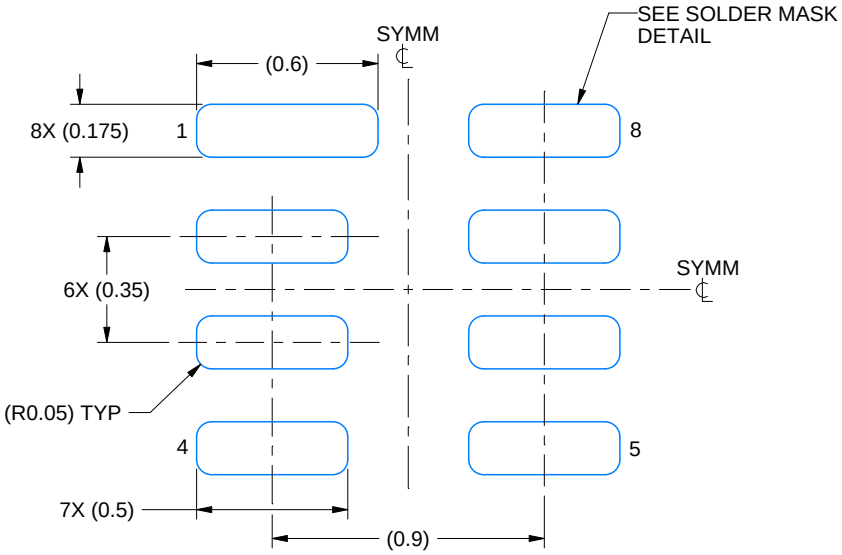
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This package complies to JEDEC MO-287 variation X2EAF.

EXAMPLE BOARD LAYOUT

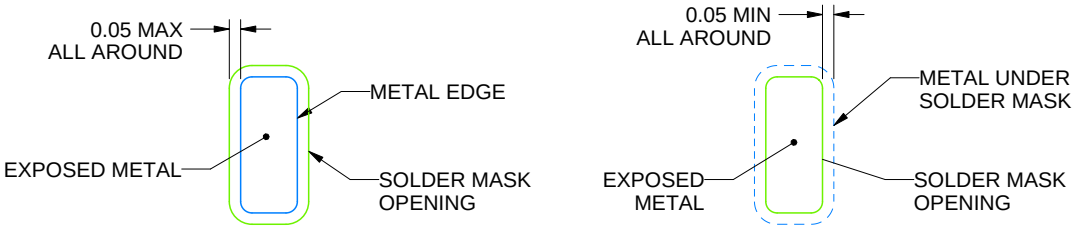
DQE0008A

X2SON - 0.4 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 40X

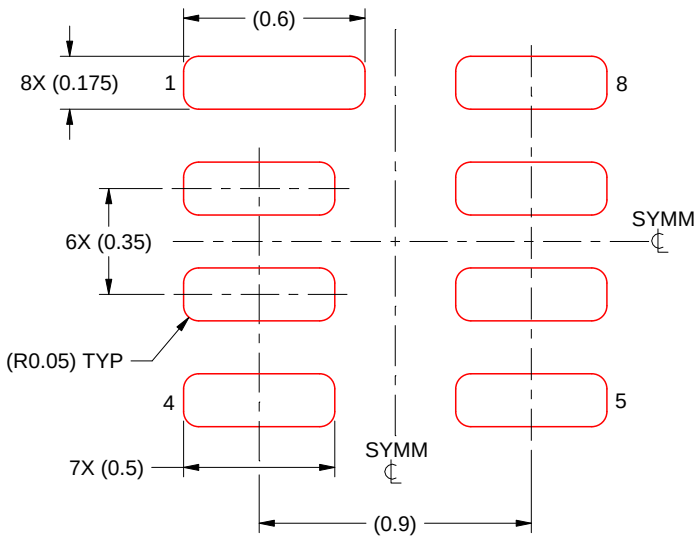


SOLDER MASK DETAILS

4225204/A 08/2019

NOTES: (continued)

4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).



SOLDER PASTE EXAMPLE
BASED ON 0.075 MM THICK STENCIL
SCALE: 40X

4225204/A 08/2019

NOTES: (continued)

5. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

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